

Ordering number:EN4538



FP211

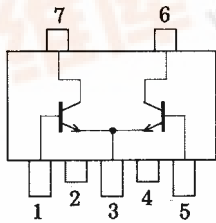
NPN Epitaxial Planar Silicon Transistor

Driver Applications

Features

- Composite type with 2 transistors (NPN) contained in one package, facilitating high-density mounting.
- The FP211 is formed with 2 chips being equivalent to the 2SD1623, placed in one package.

Electrical Connection



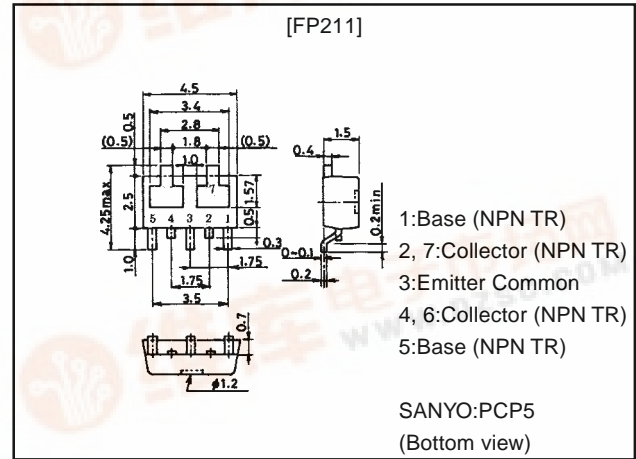
- 1:Base (NPN TR)
- 2, 7:Collector (NPN TR)
- 3:Emitter Common
- 4, 6:Collector (NPN TR)
- 5:Base (NPN TR)

(Top view)

Package Dimensions

unit:mm

2097A



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		60	V
Collector-to-Emitter Voltage	V_{CEO}		50	V
Emitter-to-Base Voltage	V_{EBO}		6	V
Collector Current	I_C		2	A
Collector Current (Pulse)	I_{CP}		4	A
Base Current	I_B		400	mA
Collector Dissipation	P_C	Mounted on ceramic board (250mm ² ×0.8mm) 1 unit	0.8	W
Total Dissipation	P_T	Mounted on ceramic board (250mm ² ×0.8mm)	1.1	W
Junction Temperature	T_J		150	°C
Storage Temperature	T_{stg}		-55 to +150	°C

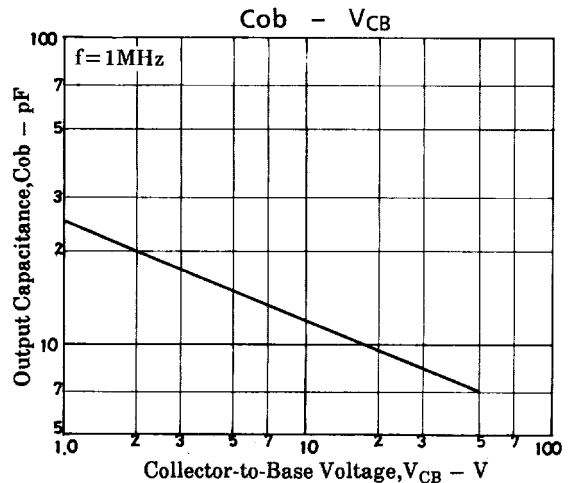
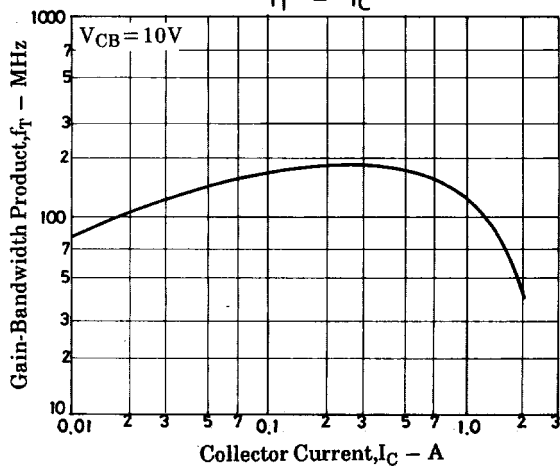
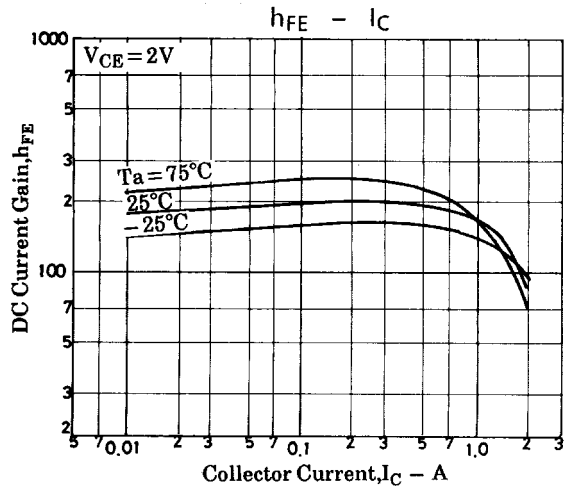
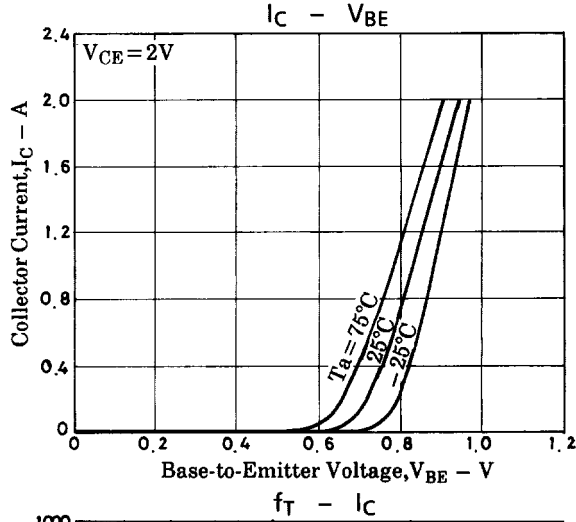
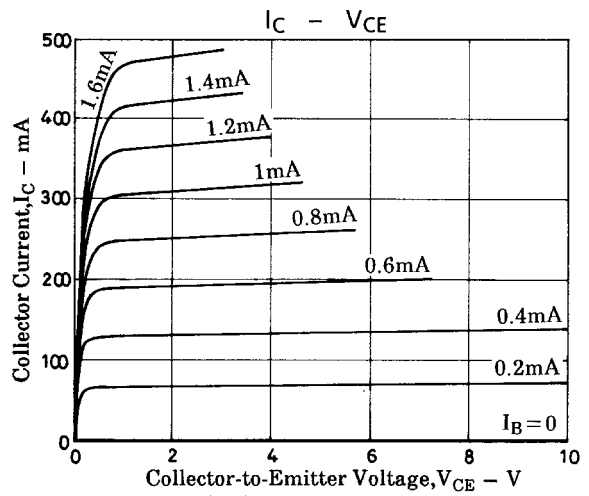
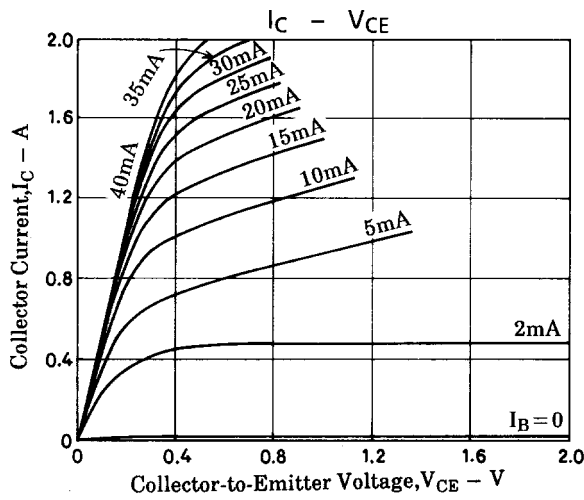
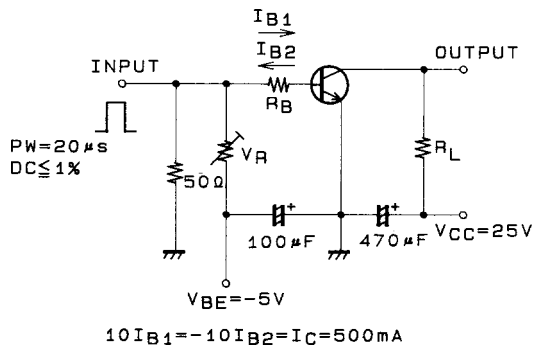
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=50V, I_E=0$			100	nA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=4V, I_C=0$			100	nA
DC Current Gain	h_{FE}	$V_{CE}=2V, I_C=100mA$	140		400	
Gain-Bandwidth Product	f_T	$V_{CE}=10V, I_C=50mA$		150		MHz
Output Capacitance	C_{ob}	$V_{CB}=10V, f=1MHz$		12		pF
C-E Saturation Voltage	$V_{CE(sat)}$	$I_C=1A, I_B=50mA$		0.15	0.4	V
B-E Saturation Voltage	$V_{BE(sat)}$	$I_C=1A, I_B=50mA$		0.9	1.2	V
C-B Breakdown Voltage	$V_{(BR)CBO}$	$I_C=10\mu A, I_E=0$	60			V
C-E Breakdown Voltage	$V_{(BR)CEO}$	$I_C=1mA, R_{BE}=\infty$	50			V
E-B Breakdown Voltage	$V_{(BR)EBO}$	$I_E=10\mu A, I_C=0$	6			V
Turn-ON Time	t_{on}	See specified Test Circuit		60		ns
Storage Time	t_{stg}	See specified Test Circuit		550		ns
Fall Time	t_f	See specified Test Circuit		30		ns

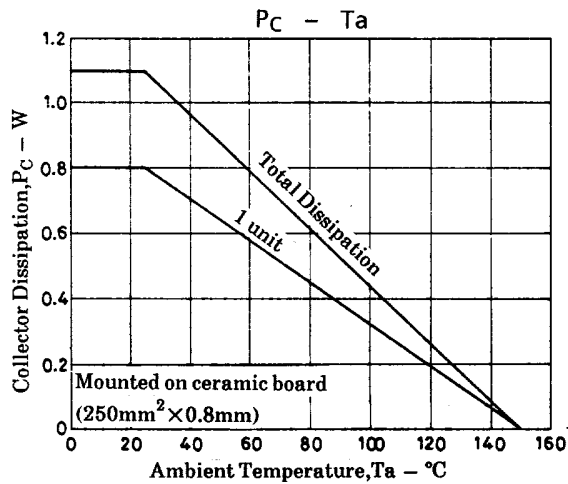
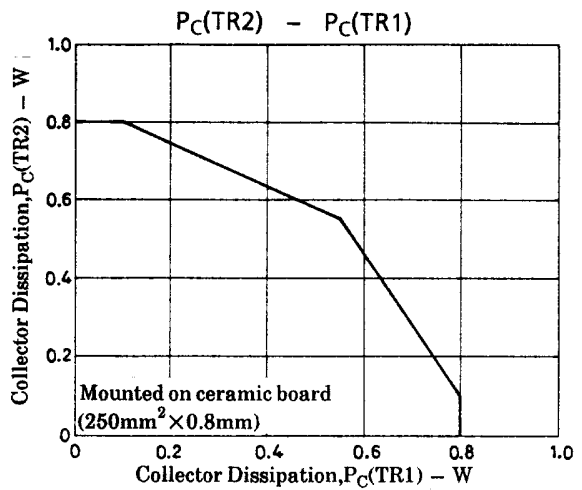
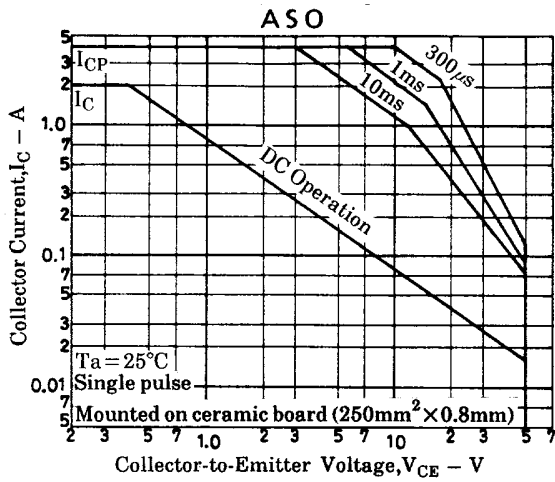
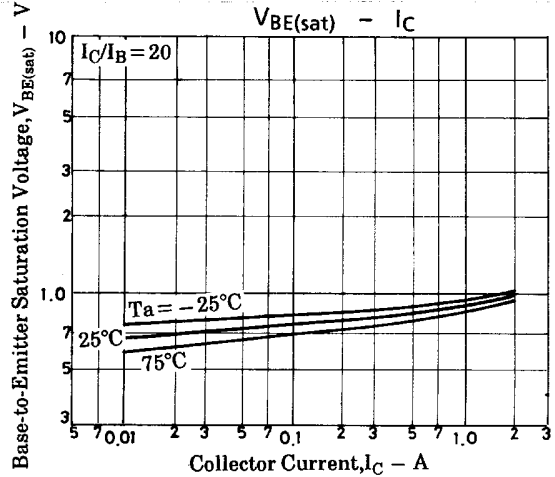
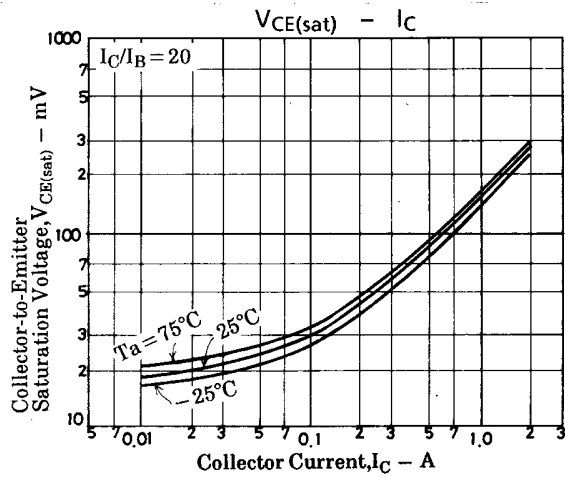
Marking:211



Switching Time Test Circuit



FP211



■ No products described or contained herein are intended for use in surgical implants, life-support systems, aerospace equipment, nuclear power control systems, vehicles, disaster/crime-prevention equipment and the like, the failure of which may directly or indirectly cause injury, death or property loss.

■ Anyone purchasing any products described or contained herein for an above-mentioned use shall:

- ① Accept full responsibility and indemnify and defend SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors and all their officers and employees, jointly and severally, against any and all claims and litigation and all damages, cost and expenses associated with such use;
- ② Not impose any responsibility for any fault or negligence which may be cited in any such claim or litigation on SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors or any of their officers and employees jointly or severally.

■ Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. SANYO believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.